

Prior art EEPROM devices only allow the voltage supplied to the control gate V_{CG} to assume one of two voltages, namely V_{CC} or the higher programming voltage of about 12V.

In another aspect of the present invention, the voltage supplied to the control gate V_{CG} is allowed to be independently and continuously variable over a wide range of voltages. This is provided by V_{PG} from the controller 1140. In particular V_{CG} in a line 1083 is fed from V_{PG} which is in turn supplied by the controller from a line 1901. Figure 27 shows V_{PG} to assume various voltages under different functions of the EEPROM.

The variability of V_{CG} is particularly advantageous in program and erase margining schemes. In program margining, the read during program verify is done with V_{CG} at a slightly higher voltage than the standard V_{CC} . This helps to place the programmed threshold well into the state by programming past the breakpoint threshold level with a slight margin. In erase verify, the cell is verified with a somewhat reduced V_{CG} to put the cell well into the "erased" state. Furthermore, margining can be used to offset the charge retention problem described earlier (Figure 16B).

As mentioned before, prior art EEPROMs typically employ V_{CC} to feed V_{CG} during program or erase verify. In order to do margining, V_{CC} itself needs to be ramped up or reduced. This practice produces inaccurate results in the reading circuits since they are also driven by V_{CC} .

In the present invention, the variability of V_{CG} independent of voltages supplied to the reading circuit produce more accurate and reliable results.

Furthermore, the wide range of V_{CG} is useful during testing and diagnostic of the EEPROM. It allows the full range of the programmed cell's threshold to be measured easily by continuing to increase V_{CG} (up to the maximum limited by the device's junction breakdown).

IN THE DRAWINGS:

Add the accompanying sheets 6-22 of drawings, in informal form, which contain additional Figures 9-27.

INVENTORSHIP:

Delete Robert D. Norman as a named inventor, in accordance with an accompanying Petition Under 37 C.F.R. 1.48(b).

IN THE CLAIMS:

Please cancel the original parent application claims 1-62, without prejudice, and substitute the following new claims therefore:

263. A method of operating a nonvolatile memory comprising the steps of: